

TLE4208G

Quad Half-Bridge Driver IC

تهيهوتوزيعقطعات

Data Sheet

Rev. 1.4, 2016-02-02

Automotive Power



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1-A Quad Half-Bridge Driver IC

TLE4208G

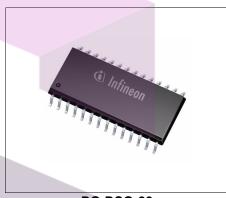




1 Overview

Features

- Driver for up to 3 motors
- Delivers up to 0.8 A continuous
- Optimized for DC motor management applications
- · Very low current consumption in stand-by (Inhibit) mode
- Low saturation voltage; typ.1.2 V total @ 25 °C; 0.4 A
- · Output protected against short circuit
- Error flag diagnosis
- Overvoltage lockout and diagnosis
- Undervoltage lockout
- CMOS/TTL compatible inputs with hysteresis
- No crossover current
- · Internal clamp diodes
- Overtemperature protection with hysteresis and diagnosis
- Enhanced power DSO-Package
- Green Product (RoHS compliant)
- AEC Qualified



PG-DSO-28

Description

The TLE4208G is a protected Quad-Half-Bridge-Driver designed specially for automotive and industrial motion control applications. The part is built using Infineous bipolar high voltage power technology DOPL.

In a cascade configuration up to three actuators (DC motors) can be connected between the four half-bridges. These four half-bridges are configured as 2 dual-half-bridges, which are supplied and controlled separately. Operation modes forward (cw), reverse (ccw), brake and high impedance are invoked from a standard interface.

The standard enhanced power PG-DSO-28 package meets the application requirements and saves PCB-board space and costs. Moreover the package is RoHS compliant.

Furthermore the built-in features like diagnosis, over- and undervoltage-lockout, short-circuit protection, overtemperature protection and the very low quiescent current in stand-by mode will open a wide range of automotive and industrial applications.

Туре	Package	Marking
TLE4208G	PG-DSO-28	TLE4208G

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Block Diagram

2 Block Diagram

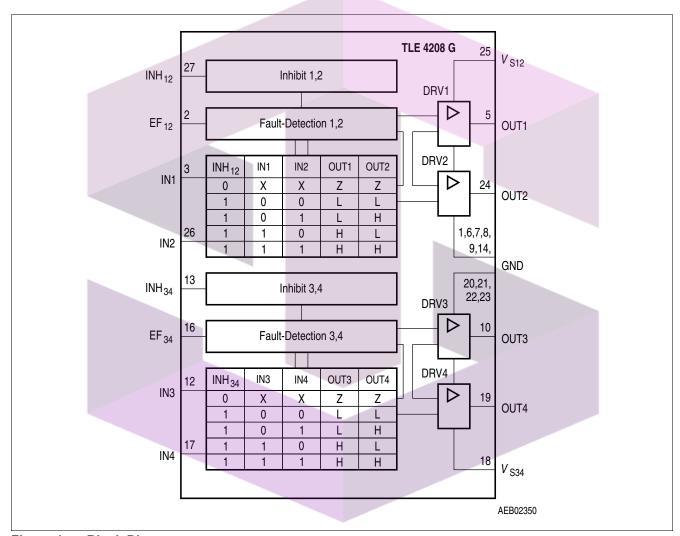


Figure 1 Block Diagram

Input Logic

Table 1 Functional Truth Table of Halfbridge 1 and 2

INH ₁₂	IN1	IN2	OUT1	OUT2	MODE
0	X	X	Z	Z	Stand-by
1	0	0	L	L	Brake LL
1	0	1 ** 1 0	400 c	H	CW
1	1	0	Н		CCW
1	1	1	Н	Н	Brake HH

Note: Half-Bridge 1 and 2 connected to a full-bridge



Block Diagram

Table 2 Functinal Truth Table of Halfbridge 3 and 4

INH ₃₄	IN3	IN4	OUT3	OUT4	MODE
0	X	X	Z	Z	Stand-by
1	0	0	L	L	Brake LL
1	0	1	L	Н	CW
1	1	0	Н	L	CCW
1	1	1	Н	Н	Brake HH

IN:

0 = Logic LOW

1 = Logic HIGH

X = Don't Care

OUT:

Z = Output in tristate condition

L = Output in sink condition

X = Output in source condition

Note: Half-Bridge 3 and 4 connected to a full-bridge

Table 3 Diagnosis

EF ₁₂ EF ₃₄		Error						
1	1	no error						
0	1	over temperature of half-bridge 1 and 2 OR						
0	1	over voltage of half-bridge 1 and 2						
1	0	over temperature of half-bridge 3 and 4 OR						
1	0	over voltage of half-bridge 3 and 4						
0	0	over temperature of all half-bridges OR						
0	0	over voltage of all half-bridge						

Pin Configuration

3 Pin Configuration

3.1 Pin Assignment

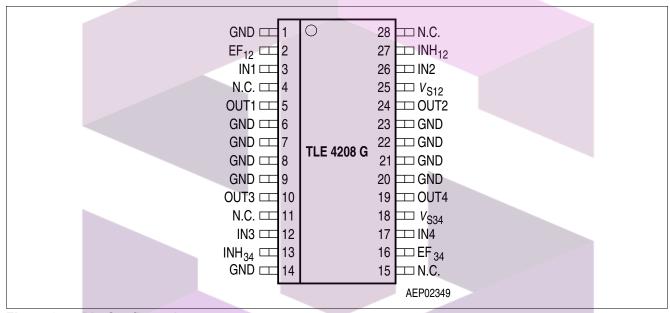


Figure 2 Pin Configuration

3.2 Pin Definitions and Functions

Pin	Symbol	Function
1, 6, 7, 8, 9, 14, 20, 21,	GND	Ground; negative reference potential for blocking capacitor
22, 23		
2	EF ₁₂	Error Flag output of half-bridges 1 and 2; open collector; low = error
3	IN1	Input channel of half-bridge 1; controls OUT 1
4, 11, 15, 28	N.C.	Not Connected
5	OUT 1	Power output of half-bridge 1; short circuit protected; with integrated clamp diodes
10	OUT 3	Power output of half-bridge 3; short circuit protected; with integrated clamp diodes
12	IN3	Input channel of half-bridge 3; controls OUT 3
13	INH ₃₄	Inhibit input of half-bridges 3 and 4; low = half-bridges 3 and 4 in stand-by



Pin Configuration

Pin	Symbol	Function					
16	EF ₃₄	Error Flag output of half-bridges 3 and 4; open collector; low = error					
17	IN4	Input channel of half-bridge 4; controls OUT 4					
18	V _{S34}	Power supply voltage of half-bridges 3 and 4; positive reference potential for blocking capacitor					
19	OUT 4	Power output of half-bridge 4; short circuit protected; with integrated clamp diodes					
24	OUT 2	Power-output of half-bridge 2; short circuit protected; with integrated clamp diodes					
25	V _{S12}	Power supply voltage of half-bridges 1 and 2; positive reference potential for blocking capacitor					
26	IN4	Input channel of half-bridge 4; controls OUT 2					
27	INH ₁₂	Inhibit input of half-bridges 1 and 2; low = half-bridges 1 and 2in stand-by					





4 General Product Characteristics

4.1 Absolute Maximum Ratings

Table 4 Absolute Maximum Ratings

 $T_{\rm j}$ = -40°C to +150°; all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values	3	Unit	Note /
		Min.	Тур.	Max.		Test Condition
Voltages		'		<u> </u>		
Supply Voltage	$V_{\rm S12},V_{\rm S34}$	-0.3	-	45	V	_
Supply Voltage	$V_{\rm S12},V_{\rm S34}$	-1	_	_	V	t < 0.5s;
						I_{S12} , $I_{S34} > -2A$
Logic input voltages	V_{I}	-5	_	20	V	${\rm OV} < V_{\rm S12}, \ V_{\rm S34} <$
(IN1; IN2; INH ₁₂ ;						45V
IN3; IN4; INH ₃₄)						
Logic output voltage	V_{EF12},V_{EF34}	-0.3	_	20	V	$0V < V_{\rm S12}, V_{\rm S34} <$
(EF ₁₂ ; EF ₃₄)						45V
Currents						
Output Current (cont.)	I_{OUT1-4}	_	-	-	Α	internally limited
Output Current (peak)	I_{OUT1-4}	-	-	_	Α	internally limited
Output Current (diode)	I_{OUT1-4}	-1	_	1	Α	-
Output Current (EF)	I _{EF12-34}	-2	_	5	mA	_
Temperatures						
Junction Temperature	$T_{\rm j}$	-40	-	150	°C	_
Storage Temperature	T_{stg}	-50	-	150	°C	-
Thermal Resistances			·		·	
Junction pin	$R_{ m thj\text{-}pin}$	-	-	25	K/W	measured to pin 7
Junction ambient	R_{thjA}	_	-	65	kV	-

Notes

- 1. Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- 2. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.



4.2 Functional Range

Table 5 Functional Range

Parameter	Symbol	Symbol		Values		Note /
		Min.	Тур.	Max.		Test Condition
Supply Voltage	$V_{\mathrm{S12}}, V_{\mathrm{S34}}$	V_{UV_OFF}	-	18	V	After $V_{\rm S12}$, $V_{\rm S34}$ rising above $V_{\rm UV_ON}$
Extended Supply Voltage Range for Operation	$V_{\mathrm{S12}}, V_{\mathrm{S34}}$	-0.3	_	V_{UV_ON}	V	Outputs in tristate
Supply Voltage transients slew rate	$V_{\mathrm{S12}}, V_{\mathrm{S34}}$	-0.3	_	V_{UV_OFF}	V/µs	Outputs in tristate
Logic input voltages (IN1; IN2; INH12; IN3; IN4; INH34)	V_1	-2	-	18	V	-
Junction Temperature	T_{j}	-40	_	150	°C	_

Note: Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the Electrical Characteristics table.





4.3 General Electrical Characteristics

4.3.1 Electrical Characteristics

Table 6 Electrical Characteristics

 $V_{\rm S12}$ = $V_{\rm S34}$ = 8 V to 18 V, INH₁₂ = INH₃₄ = HIGH; I_{OUT1-4} = 0A; $T_{\rm j}$ = -40°C to +150°, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values			Note /	
		Min. Ty		Max.		Test Condition	
Current Consumption		<u> </u>					
$INH_{12} = INH_{34} = LOW$							
Quiescent current	I_{S}	_	_	100	μΑ	$I_{\rm S} = I_{\rm S12} + I_{\rm S34}$	
Quiescent current	I_{S}	-	20	40	μΑ	$I_{\rm S} = I_{\rm S12} + I_{\rm S34};$	
						$V_{S12} = V_{S34} = 13.2$ $T_i = 25 ^{\circ}\text{C}$	
INH ₁₂ = HIGH and INH ₃₄ = LOW	or INH ₄₀ = LOV	│ V and INF	l _{or} = HIGH			1 _j - 25 C	
Supply current	$I_{\rm S12}, I_{\rm S34}$	_	10	20	mA		
Supply current	I _{S12} , I _{S34}	_	_	30	mA	$I_{\text{OUT1/3}} = 0.4A$	
cappi, cament	1512, 1534				1	$I_{\text{OUT2/4}} = -0.4A$	
Supply current	$I_{\rm S12}, I_{\rm S34}$	_	_	50	mA	$I_{\text{OUT1/3}} = 0.8A$	
						$I_{\text{OUT2/4}} = -0.8A$	
Over- and Under Voltage Locko	out						
UV Switch ON voltage	V_{UVON}	7-	6.5	7.5	V	$V_{\rm S12}, V_{\rm S34}$ increas	
UV Switch OFF voltage	V_{UV_OFF}	5	6	_	V	$V_{\rm S12}, V_{\rm S34}$ decreas	
UV ON/ OFF hysteresis	V_{UV_HY}	-	0.5	_	V	V _{UV ON} - V _{UV OFF}	
OV Switch OFF voltage	V_{OVOFF}	_	20	24	V	$V_{\rm S12}, V_{\rm S34}$ increas	
OV Switch ON voltage	V_{OV_ON}	18	19.5	_	V	$V_{\rm S12}, V_{\rm S34}$ decreas	
OV ON/ OFF hysteresis	V_{OV_HY}	_	0.5	_	V	$V_{ m OVOFF}$ - $V_{ m OVON}$	
Outputs OUT1; OUT2; OUT3; O	UT4						
Saturation Voltages							
Source (upper)	V_{SAT_U}	-	0.85	1.15	V	$T_{\rm j}$ = 25°C	
I_{OUT12} , $I_{OUT34} = -0.2 \text{ A}$							
Source (upper)	V_{SAT_U}	-	0.90	1.20	V	T _j = 25°C	
$I_{OUT12}, I_{OUT34} = -0.4 \text{ A}$	17		4.40	4.50	.,	W. 0500	
Sink (upper)	V_{SAT_U}	-	1.10	1.50	V	T _j = 25°C	
$\frac{I_{OUT12}, I_{OUT34} = -0.8 \text{ A}}{\text{Sink (lower)}}$	V		0.15	0.23	V	<i>T</i> _i = 25°C	
$I_{OUT12}, I_{OUT34} = 0.2 A$	V_{SAT_L}	_	0.13	0.23	V	1 _j - 25 C	
Sink (lower)	V_{SAT_L}	1 - 1	0.25	0.40	V	<i>T</i> _i = 25°C	
$I_{OUT12}, I_{OUT34} = 0.4 \text{ A}$	· SAI_L			2	1 10	لمولد	
Sink (lower)	V_{SAT_L}	_	0.45	0.75	V	T _i = 25°C	
I_{OUT12} , $I_{OUT34} = 0.8 A$	5, 11_E					,	
Total Drop	V_{SAT}	-	1	1.4	V	$V_{\text{SAT}} = V_{\text{SAT_U}} + V_{\text{SAT_U}}$	
I_{OUT12} , $I_{OUT34} = 0.2 A$							



Table 6 Electrical Characteristics

 $V_{\rm S12}$ = $V_{\rm S34}$ = 8 V to 18 V, INH₁₂ = INH₃₄ = HIGH; I_{OUT1-4} = 0A; $T_{\rm j}$ = -40°C to +150°, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Parameter	Symbol		Values			Note /	
		Min.	Тур.	Max.		Test Condition	
Total Drop I _{OUT12} , I _{OUT34} = 0.4 A	V_{SAT}	-	1.2	1.7	V	$V_{\text{SAT}} = V_{\text{SAT_U}} + V_{\text{SAT_L}}$	
Total Drop I _{OUT12} , I _{OUT34} = 0.8 A	V_{SAT}	-	1.6	2.5	V	$V_{\text{SAT}} = V_{\text{SAT_U}} + V_{\text{SAT_L}}$	
Clamp Diodes							
Forward voltage; upper	$V_{\sf FU}$	_	1	1.5	V	$I_{F} = 0.4A$	
Upper leakage current	I_{LKU}	_	_	5	mA	$I_{\rm F} = 0.4 {\rm A}^{1)}$	
Forward voltage; lower	V_{FL}	_	0.9	1.4	V	$I_{F} = 0.4A$	
Input Interface Logic Inputs IN1; IN2; IN3; IN4					·		
H-input voltage	V_{IH}	_	2.0	3.0	V	_	
L-input voltage	V_{IL}	1.0	1.5	_	V	-	
Hysteresis of input voltage	V_{IHY}	_	0.5	_	V	-	
H-input current	I_{IH}	-2	_	10	μΑ	V _I = 5V	
L-input current	I_{IL}	-100	-20	-5	μΑ	$V_{\rm I}$ = 0V	
Logic Inputs INH ₁₂ ; INH ₃₄							
H-input voltage	V_{IH}	-	2.7	3.5	V	_	
L-input voltage	V_{IL}	1.0	2.0	_	V	_	
Hysteresis of input voltage	V_{IHY}	-	0.7	_	V	-	
H-input current	I_{IH}	_	100	250	μΑ	$V_{\rm INH}$ = 5V	
L-input current	I_{IL}	-10	_	10	μΑ	$V_{INH} = OV$	
Error Flags EF ₁₂ ; EF ₃₄						•	
L-output voltage level	V_{EFL}	_	0.2	0.4	V	I_{EF} = 2 mA	
Leakage current	I_{EFLK}	_	_	10	μΑ	0V < V _{EF} < 7V	
Thermal Shutdown							
Thermal shutdown junction temperature	T_{jSD}	150	175	200	°C		
Thermal switch-on junction temperature	T_{jSO}	120	-	170	°C		
Temperature hysteresis	ΔT	_	30	_	K	_	
1) Not subject to production test, on	a aifia al lavo al a ai ava					I .	

¹⁾ Not subject to production test, specified by design

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Application Information

5 Application Information

Note: The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device.

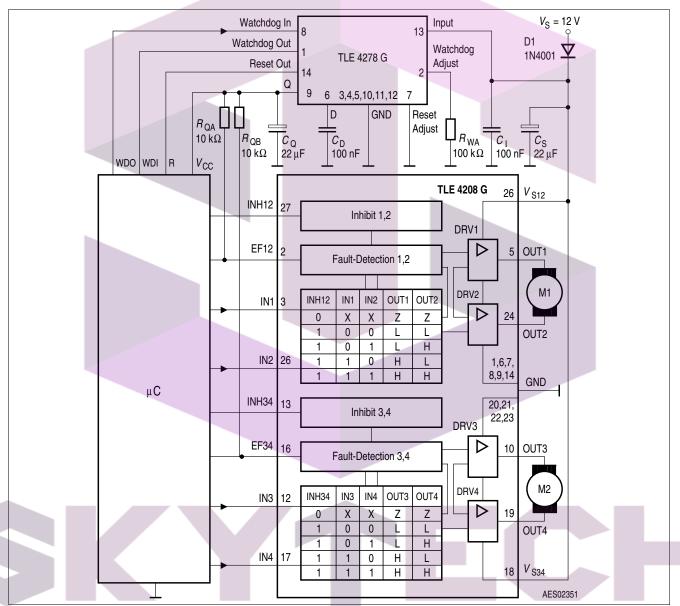


Figure 3 Application Circuit 1 (Device is used as Dual-Full-Bridge-Driver)

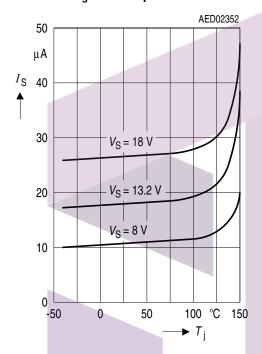
Note: This is a very simplified example of an application circuit. The function must be verified in the real application.



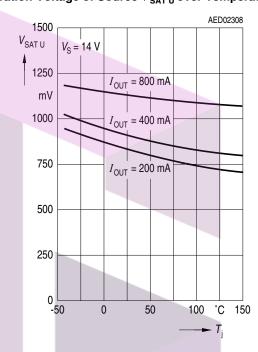
Application Information

Diagrams

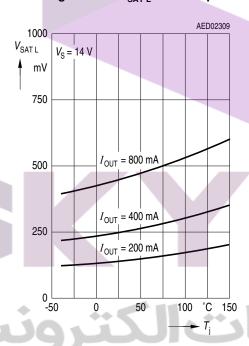
Quiescent current $I_{\rm S}$ over Temperature



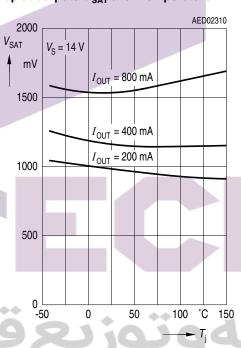
Saturation Voltage of Source $V_{\mathrm{SAT}\,\mathrm{U}}$ over Temperature



Saturation Voltage of Sink V_{SATL} over Temperature



Total Drop at outputs V_{SAT} over Temperature





Package Outlines

6 Package Outlines

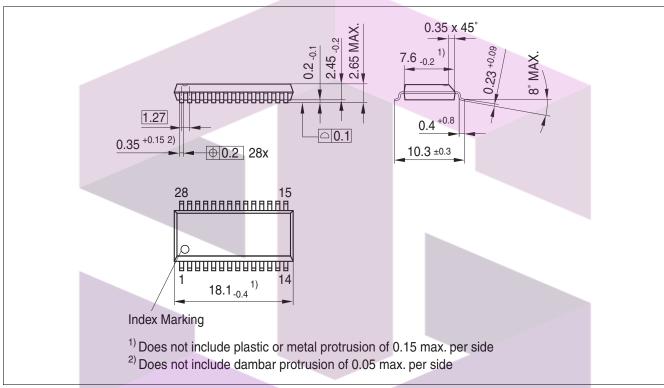


Figure 4 PG-DSO-28

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).



For further information on alternative packages, please visit our website: http://www.infineon.com/packages.

Dimensions in mm

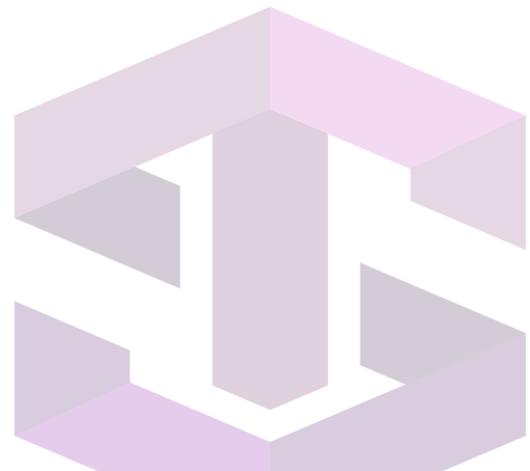


Revision History

7 Revision History

Revision	Date	Changes					
Rev. 1.4	2016-02-02	Correction of typographical errors Page 10: VOFF_OFF and VOFF_ON are inverted. No change of the device behavior. Page 10,11: VS1, respectively VS2, renamed VS12 and VS34					
Rev. 1.3	2014-02-12	Updated package designation and to latest data sheet formatting					
Rev. 1.2	2011-04-11	Updated package designation to reflect various production sites.					
Rev. 1.1	2008-02-04	Initial version of RoHS-compliant derivate of TLE4208G Page 1: added AEC certified statement Page 1 and 13: added RoHS compliance statement and Green product feature Page 1 and 3: Editorial change: deleted "fully" (The term "fully protected" often leads to misunderstandings as it is unclear with respect to which parameters). Page 1 and 14: Package changed to RoHS compliant version Page 15: added Revision History, updated Legal Disclaimer					





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